INFLUENCE OF NANO-AG ADDITION ON PHASE FORMATION AND EXCESS CONDUCTIVITY ANALYSIS OF (CU0.5TL0.5)-1223 SUPERCONDUCTING PHASE

Nayera Mohammed
Faculty of Science, Alexandria University, Alexandria, Egypt, nysharaf@yahoo.com

Seham Mahmoud
Faculty of Science, Alexandria University, Alexandria, Egypt, gomaagaber@hotmail.com

Weleed Abdeen
Faculty of Science, Alexandria University, Alexandria, Egypt & University College at Al-Gamom, Umm Al-Qura University, Saudi Arabia, waabdeen@uqu.edu.sa

Marwa Hasebbo
Faculty of Science, Alexandria University, Alexandria, Egypt, marwahaseboo@yahoo.com

Follow this and additional works at: https://digitalcommons.bau.edu.lb/stjournal

Part of the Architecture Commons, Business Commons, Engineering Commons, and the Physical Sciences and Mathematics Commons

Recommended Citation
Mohammed, Nayera; Mahmoud, Seham; Abdeen, Weleed; and Hasebbo, Marwa (2019) "INFLUENCE OF NANO-AG ADDITION ON PHASE FORMATION AND EXCESS CONDUCTIVITY ANALYSIS OF (CU0.5TL0.5)-1223 SUPERCONDUCTING PHASE," BAU Journal - Science and Technology: Vol. 1: Iss. 1, Article 6.
DOI: https://doi.org/10.54729/2959-331X.1007

This Article is brought to you for free and open access by the BAU Journals at Digital Commons @ BAU. It has been accepted for inclusion in BAU Journal - Science and Technology by an authorized editor of Digital Commons @ BAU. For more information, please contact ibtihal@bau.edu.lb.
1. INTRODUCTION

Cu-1223 phase prepared at 4GPa with $T_c = 68$ K and $\Gamma$ about 1.7 [1-3]. Regrettably, such preparation impedes Cu-1223 from a wide range of applications. Replacing Tl at the Cu atoms in the charge reservoir layer develops (Cu$_{0.5}$Tl$_{1.5}$)-1223 that can be synthesized at normal pressure. This compound is characterized by low $\Gamma$, high critical current density $J_c$ and high superconducting transition temperature $T_c$ [4, 5]. One of a promising application is (Cu$_{0.5}$Tl$_{0.5}$)-1223, because of its amazing electrical properties, such as high values of $T_c$ (113-132 K) and $J_c$, and values of low values of $\Gamma$ ($\Gamma = 4$) [4]. The crystal structure of (Cu$_{0.5}$Tl$_{0.5}$)-1223 with P4/mmm space group with tetragonal unit cell [6]. This phase consists of 3 CuO$_2$-planes and a semi insulating charge reservoir layer (Cu$_{0.5}$Tl$_{0.5}$)Ba$_2$O$_{1-d}$ in its unit cell.

The study of the excess conductivity attributable to thermal fluctuations is crucial for knowing the intrinsic superconducting characteristics and dimensionality of HTSCs. Superconducting properties depend on both the intrinsic properties such as conduction dimensionality and coherence lengths, and the extrinsic properties such as the grain morphology of the samples. The excess conductivity is analyzed by several models such as Aslamazove and Larkin (AL), Maki-Thompson (MT), Lawrence and Doniach (LD) and Hikami-Larkin (HL) [7-10]. AL theory and LD model were applied to study the excess conductivity of different samples by several groups [11-21]. In AL model, the excess conductivity originates from the formation of Cooper pairs above $T_c$. The LD model is the modification of AL theory for polycrystalline samples that expecting a crossover from 2D to 3D conductivity, as temperature move towards $T_c$. On other hand and according to MT model, the excess conductivity arises from the scattering of fluctuating pairs from conventional electrons and hence described the region of abstemious pair breaking.

By adding nano-particles to HTSCs, there is a great chance for enhancing the flux pinning and $J_c$ values, since the size of nano-particles is greater than the coherence length $\xi$ and smaller than the penetration depth $\lambda$, leading to powerful interaction between flux line network and nano-particles. A proper addition of nano-particles such as ZrO$_2$ [22], Al$_2$O$_3$ [23, 24], and NiFe$_2$O$_4$ [25] in (Bi,Pb)-2223, and ZrO$_2$and ZnO [26] in Gd-123 acted as effective flux pinning centers and improved $J_c$. Also, nano-particles addition to (Cu$_{0.5}$Tl$_{0.5}$)-1223, such as SnO$_2$ [27], In$_2$O$_3$ [27] and Fe$_2$O$_3$ [28], lowered porosity and improved both, volume fraction and Vickers microhardness. Moreover, adding nano-particles of CuO, BaO and CaO [29] to (Cu$_{0.5}$Tl$_{0.5}$)-1223 improved superconducting properties such as $T_c$, intergrain connectivity and magnitude of diamagnetism. adding low amounts of nano-ZnO to (Cu$_{0.5}$Tl$_{0.5}$)Pb$_{0.25}$Tl$_{0.25}$-1223 [30] enhanced the volume fraction, $T_c$, $J_c$ and the melting temperature. The superconducting parameters of Gd-123 [31] added with nano-CoFe$_2$O$_4$, Y-123 [32] added with Zn$_{0.95}$Mn$_{0.05}$O and ZnO, and CuTi-1223[33] added with nano-CuO were determined from excess conductivity. The results showed that the low concentration of nano-sized addition improved $J_c$ and the critical magnetic fields ($B_c$, $B_{c1}$ and $B_{c2}$) and inter-grain coupling $\nu$.

The present work analyzed the impact of adding nano-Ag to the phase formation and the behavior of thermal fluctuations conductivity above $T_c$. The superconducting parameters such as $\xi_c(0)$, $\nu_F$, $E_F$ and $\nu$ of (Cu$_{0.5}$Tl$_{0.5}$)-1223 superconducting phase were calculated. For this study, superconducting samples of type Cu$_{0.5}$Tl$_{0.5}$Ba$_2$Ca$_2$Cu$_3$O$_{10-\delta}$ with different concentrations of nano-Ag addition were prepared and investigated using XRD, SEM and electrical resistivity measurement.

2. EXPERIMENTAL TECHNIQUE

Superconducting samples of type Cu0.5Tl0.5Ba2Ca2Cu3O10-δ added with nano-Ag were synthesized using single step solid-state reaction technique. Grinding stoichiometric ratios of oxides of TiO2, BaO2, CaO, and CuO, of high purity, in agate mortar. To and get a homogenous mixture, the grinded powder were twice sifted using 85 µm sieve. Finally, nano-Ag (Aldrich, 20-40 nm) was mixed with different amounts (0.0, 0.5, 1.0, 1.5, 2.0 and 3.0 wt.%) with the resulted powder. Then, the obtained powder pressed into a disc of 15 mm diameter and a thickness of about 3 mm. The pressed disc was wrap up in a silver foil to decrease the loss in thallium through preparation. Then, disc was heated in sealed quartz tubes (7.5 mm radius and 120 mm length) at 4 oC/min to 760 oC, followed by heating to 850 oC at 2 oC/min, then the samples held at 850 oC for 5 hours. Slowly cooling to room temperature, by furnace cooling is the last stage.

Sample characterization and the electrical resistivity measurements where discussed in a previous work [17].
3. RESULTS AND DISCUSSION

The XRD patterns of (nano-Ag)xCu0.5Tl0.5Ba2Ca2Cu3O10-δ, with 0.0 ≤ x ≤ 3.0 wt.% are shown in Fig. 1. The XRD patterns of the samples with x ≤ 2.0 wt.% indicate the formation of a single of (Cu0.5Tl0.5)-1223 with tetragonal P4/mmm symmetry. Small quantities of secondary phases are appeared, such as (Cu0.5Tl0.5)-1212 and Ba2Cu3O5.9. On the other hand, XRD patterns of (nano-Ag)3.0wt.%Cu0.5Tl0.5Ba2Ca2Cu3O10-δ sample indicate the formation of (Cu0.5Tl0.5)-1212 phase with space group P4/mmm and tetragonal unit cell [34], with small amount of BaCuO2. This means that a phase change from (Cu0.5Tl0.5)-1223 phase to (Cu0.5Tl0.5)-1212 phase occurred at x = 3.0 wt.%. Similar result was noted for Y-123 when adding Ag, that might substitute Cu [35], and when added by nano-Al2O3 that could fill Y and Cu(1) sites [36], and for (Bi,Pb)-2223 phase when adding high amounts of nano-SnO2 that changes (Bi,Pb)-2223 to (Bi,Pb)-2212 phase [37]. It should me mentioned that no peaks corresponds to nano-Ag or Ag-based compounds were detected by X-ray diffraction. Similar results were noticed for (Cu0.5Tl0.5)-1223 added by nano-SnO2 [38] and nano-CuO [33] and for (Bi,Pb)-2223 added by nano-NiFe2O4 [25].

![XRD patterns for (nano-Ag)xCu0.5Tl0.5Ba2Ca2Cu3O10-δ, 0.0 ≤ x ≤ 3.0 wt.%](image)

Fig.1: The XRD patterns for (nano-Ag)xCu0.5Tl0.5Ba2Ca2Cu3O10-δ, 0.0 ≤ x ≤ 3.0 wt.%.

The calculated volume fractions are listed in table 1. It is clear that the volume fraction of (Cu0.5Tl0.5)-1223 increases as the x increases up to 1.5 wt.% and then it decreases, so the high addition retards the formation rate of (Cu0.5Tl0.5)-1223 phase. Hence, the viscosity of the forming transient liquid at the reaction temperature is affected by the addition of nano-Ag, its homogeneity and hence the phase formation rate were also affected. Similar trend were noticed for (Bi,Pb)-2223 phase, when adding nano-Al2O3 [24], and when also, adding nano-MgO [39] and for (Cu0.25Tl0.75)-1234 phase added by nano-MgO [40].
Table 1. The volume fractions percentage of (Cu$_{0.5}$Tl$_{0.5}$)$_{1223}$, (Cu$_{0.5}$Tl$_{0.5}$)$_{1212}$, Ba$_2$Cu$_3$O$_{5.9}$ and BaCuO$_2$ phases and the lattice parameters for (nano-Ag)$_x$Cu$_{0.5}$Tl$_{0.5}$Ba$_2$Ca$_2$Cu$_3$O$_{10-\delta}$ with x.

<table>
<thead>
<tr>
<th>x (wt.%)</th>
<th>The volume fractions (%)</th>
<th>The lattice parameters</th>
<th>a (Å)</th>
<th>c (Å)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>(Cu$<em>{0.5}$Tl$</em>{0.5}$)$_{1223}$</td>
<td>(Cu$<em>{0.5}$Tl$</em>{0.5}$)$_{1212}$</td>
<td>Ba$_2$Cu$<em>3$O$</em>{5.9}$</td>
<td>BaCuO$_2$</td>
</tr>
<tr>
<td>0.0</td>
<td>88.23</td>
<td>6.36</td>
<td>5.41</td>
<td>0.00</td>
</tr>
<tr>
<td>0.5</td>
<td>89.61</td>
<td>5.59</td>
<td>4.75</td>
<td>0.00</td>
</tr>
<tr>
<td>1.0</td>
<td>90.03</td>
<td>5.50</td>
<td>4.47</td>
<td>0.00</td>
</tr>
<tr>
<td>1.5</td>
<td>91.55</td>
<td>5.29</td>
<td>3.16</td>
<td>0.00</td>
</tr>
<tr>
<td>2.0</td>
<td>89.61</td>
<td>5.59</td>
<td>4.80</td>
<td>0.00</td>
</tr>
<tr>
<td>3.0</td>
<td>35.20</td>
<td>61.65</td>
<td>0.00</td>
<td>3.15</td>
</tr>
</tbody>
</table>

The least squares method is used to determine the lattice parameters “a” and “c”, that are recorded in Table 1. From these results, it is clear that no considerable difference between the lattice constants for samples with x ≤ 2.0 wt.% with respect to the sample with x = 0.0 wt.%. This can be explained as nano-Ag does not enter the (Cu$_{0.5}$Tl$_{0.5}$)Ba$_2$Cu$_2$O$_{3010-\delta}$ crystal structure. Similar results were noticed for (Bi,Pb)$_{2223}$ when adding nano-Gd [41], and nano-NiFe$_2$O$_4$ [25], and for (Cu, Tl)$_{1223}$ added by nano-ZnFe$_2$O$_4$ [42]. For x = 3.0 wt.%, “c” reduces to become nearer to that of (Cu$_{0.5}$Tl$_{0.5}$)$_{1212}$ [34]. This behavior suggests that Cu site could be filled by Ag. Similar conclusion was noticed for Y-123 when adding Ag [36] and nano-Al$_2$O$_3$ [37].

Typical SEM micrographs for (nano-Ag)$_x$Cu$_{0.5}$Tl$_{0.5}$Ba$_2$Ca$_2$Cu$_3$O$_{10-\delta}$, for x = 0.0, 0.5, 1.5 and 3.0 wt.% are shown in Figs. 2(a), (b), (c) and (d), respectively. The micromorphology shows that the samples have a rectangular plate shape that signify (Cu$_{0.5}$Tl$_{0.5}$)$_{1223}$ phase [43]. Few number of irregular shaped and spherical grains which indicate to (Cu$_{0.5}$Tl$_{0.5}$)$_{1212}$ phase [44] and the impurity phases Ba$_2$Cu$_3$O$_{5.9}$ [44] and BaCuO$_2$ [43]. It is obvious that the grains corresponds to (Cu$_{0.5}$Tl$_{0.5}$)$_{1212}$ phase reduce, while those (Cu$_{0.5}$Tl$_{0.5}$)$_{1223}$ phase raise and are more aligned up to x = 1.5 wt.%. This means that adding of small amount improves the (Cu$_{0.5}$Tl$_{0.5}$)$_{1223}$ phase formation. Not far from the results obtained for (Bi,Pb)$_{2223}$ phase substituted by Ag [45]. The number of irregular-shaped plates for (nano-Ag)$_{3.0}$wt.%Cu$_{0.5}$Tl$_{0.5}$Ba$_2$Cu$_2$O$_{3010-\delta}$, Fig. 2(d), increase, improving (Cu$_{0.5}$Tl$_{0.5}$)$_{1212}$ phase formation.

Fig. 2: SEM images for (nano-Ag)$_x$Cu$_{0.5}$Tl$_{0.5}$Ba$_2$Ca$_2$Cu$_3$O$_{10-\delta}$ for x (a) 0.0 wt.%; (b) 0.5 wt.%; (c) 1.5 wt.%; (d) 3.0 wt.%.
The temperature dependence of the electrical resistivity for all prepared samples in the temperature range \( T_0 \leq T \leq 300 \) K is shown in Fig. 3. All prepared samples show a linear behavior at high temperatures, then a sharp transition occurred as the temperature is decreased. Martin et al. [46] using the Bloch-Gruneisen formula to fit the T-linear electrical resistivity in Bi-cuprates, which gave an unreasonably low Debye temperature of less than 35 K. Bosons and fermions are quarantined to the CuO-planes, and the electrical resistivity in the plane is generated by the scattering of the bosons from fermions, which will follow the linear temperature dependence [47]. By using the marginal Fermi liquid theory by Varma et al. [48] and the nested Fermi liquid by Virosztek and Ruvalds [49], one can explain the T-linear electrical resistivity.

\[ \rho_n = \rho_0 + QT, \]

where \( Q \) is resistivity temperature coefficient and \( \rho_0 \) is residual resistivity. Table 2 summarizes \( \rho_n, \rho_0, Q, T_c \) and the transition width \( \Delta T \).

<table>
<thead>
<tr>
<th>( x ) (wt.%)</th>
<th>( \rho_n ) (mΩ·cm)</th>
<th>( \rho_0 ) (mΩ·cm)</th>
<th>( Q ) (mΩ·cm·K(^{-1}))</th>
<th>( T_c ) (K)</th>
<th>( \Delta T = T_c - T_0 ) (K)</th>
<th>( T_{cm}^{mf} ) (K)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.0</td>
<td>3.225</td>
<td>0.242</td>
<td>0.010</td>
<td>111.27</td>
<td>12.77</td>
<td>112</td>
</tr>
<tr>
<td>0.5</td>
<td>2.879</td>
<td>0.231</td>
<td>0.009</td>
<td>114.34</td>
<td>10.84</td>
<td>115.40</td>
</tr>
<tr>
<td>1</td>
<td>2.747</td>
<td>0.141</td>
<td>0.009</td>
<td>113.14</td>
<td>10.84</td>
<td>115.60</td>
</tr>
<tr>
<td>1.5</td>
<td>2.559</td>
<td>0.125</td>
<td>0.008</td>
<td>120.93</td>
<td>9.33</td>
<td>121.20</td>
</tr>
<tr>
<td>2.0</td>
<td>4.706</td>
<td>0.337</td>
<td>0.014</td>
<td>117.29</td>
<td>11.29</td>
<td>117.60</td>
</tr>
<tr>
<td>3.0</td>
<td>5.558</td>
<td>1.252</td>
<td>0.015</td>
<td>107.87</td>
<td>15.28</td>
<td>108.00</td>
</tr>
</tbody>
</table>

It is clear from Fig. 3 that there is a tiny curvature in the resistivity beyond \( T_c \) that distinguishes the superconducting thermodynamic fluctuations [50]. The data for the samples with \( x \leq 2.0 \) wt.% indicates the formation of a single phase of \((Cu0.5Tl0.5)-1223\), since the transition to zero resistivity temperature is sharp. While a broaden transition was noticed for the sample \((nano-Ag)3.0wt.%Cu0.5Tl0.5Ba2Ca2Cu3O10-\delta\), indicating the formation of secondary phase. The electrical resistivity data for all prepared samples are fitted using:

It is clear that both \( \rho_n \) and \( \rho_0 \) decrease with increasing \( x \) till 1.5 wt.\%, then they increase as \( x \) increases. The reduction in \( \rho_n \) could be attributed to the diffusion of nano-Ag over the pore surfaces and the grain boundaries. Similar results noticed for Bi-2223 phase added byAg2CO3 [51] and for Y-123 phase added by nano-Al2O3 [37]. These results are in good agreement with those obtained from SEM. While the rise of \( \rho_n \) may be due to the rise in the grain boundaries and impurities scattering. The small values of \( \rho_0 \) indicate that the high quality of the prepared samples and have less defects.
These results are in good agreement with results determined from X-ray and scanning electron microscopy. The resistivity temperature coefficient values change slightly till \( x = 1.5 \) wt.%, that could be explained as the nano-Ag additions don’t alter the charge carriers-concentrations, since it does not enter the crystal structure of \((\text{Cu0.5Tl0.5})-1223\). The increase in the resistivity temperature coefficient may be attributed to the phase change and the reduction in the charge carriers-concentrations. It is well known that the granular HTSC’s have a well-defined \( T_c \). It is determined from the first derivative of \( \rho(T) \) with respect to the temperature, and the maximum of \( \frac{d\rho(T)}{dT} \) corresponds to \( T_c \) [52], which are shown in the Fig. 4 and listed in table 2. It is clear that the superconducting transition temperature values increase as \( x \) increasing up to 1.5 wt.% which may be described according to the increase in the volume fraction of \((\text{Cu0.5Tl0.5})-1223\). The decrease of \( T_c \) for \( x > 1.5 \) wt.% may be due to the phase change from \((\text{Cu0.5Tl0.5})-1223\) phase to \((\text{Cu0.5Tl0.5})-1212\) phase or the blocking of mobile holes [37]. Table 2 shows the effect of different nano-particles SnO2 [27], In2O3 [27] and Fe2O3 [28] addition on enhancement of \( T_c \) and volume fraction for \((\text{Cu0.5Tl0.5})-1223\) superconducting phase. It is obvious that there is no direct relation between the increase of \( T_c \) and volume fraction. So, the increase in the volume fraction is not the main factor for increasing \( T_c \). This suggested that the alignment of grains and grains connectivity could play the roles for enhancing \( T_c \). Abou-Aly et al. [53] noted similar results, who found that the maximum improvement of \( T_c \) for (Bi,Pb)-2223 when adding by nano-SnO2.

The excess conductivity for \((\text{nano-Ag})_{x}\text{Cu}_{0.5}\text{Tl}_{0.5}\text{Ba}_{2}\text{Ca}_{2}\text{Cu}_{3}\text{O}_{10-\delta}\), with \( 0.0 \leq x \leq 3.0 \) wt.%. above \( T_c \) was studied in the scope of AL theory and LD model. The excess conductivity is expressed as:

\[
\Delta \sigma_{AL} = A t^\alpha
\]

where, \( t \) is a reduced temperature \( \left( t = \frac{T-T_{cmf}}{T_{cmf}} \right) \), \( T_{cmf}^{mf} \) is mean field critical temperature, \( \alpha \) is the dimensional exponent, \( \alpha = -0.3 \), for 3D fluctuations, \( \alpha = -0.5 \) for 3D fluctuations and \( \alpha = -1.0 \) for 2D fluctuations that follows the relationship; Dimensionality \( D = 2\left[2 + \alpha \left(D\right)\right] \) [54]. \( A \) is the temperature independent parameter has two values, \( \frac{\eta}{32 \xi^2 c(0)} \) for 3D where, \( \xi_c(0) \) is the zero-temperature coherence length along the c-axis and \( \frac{\eta^2 \xi^2 c(0)}{16 \eta d} \) for 2D where, \( d \) is the effective layer thickness of superconducting layers (\( d \sim 15 \) Å for \((\text{Cu0.5Tl0.5})-1223\) and \( d \sim 12 \) Å for \((\text{Cu0.5Tl0.5})-1212\)). The temperature at which a crossover from three to two dimensional takes place is given by:

\[
T_{LD} = T_{cmf}^{mf} \left\{ 1 + \left( \frac{2 \xi_c(0)}{d} \right)^2 \right\}
\]
The excess conductivity $\Delta \sigma$ induced by thermal fluctuation is calculated by:

$$\Delta \sigma = \sigma_m(T) - \sigma_n(T),$$

where, $\sigma_m(T)$ and $\sigma_n(T)$ are the measured and normal state extrapolated conductivity, respectively.

$T_{cmf}$ values are determined by extrapolation of straight line in $\Delta\sigma^{-2}$ versus $T$ plots shown in Figs. 5(a), (b) and (c) and they are recorded in table 3. This method was reported by Han et al. [55] considering the 3D behavior of an anisotropic superconductor near $T_c$ when $\xi(T) = \xi(T_c) t^{1/2}$ become large. In this region $\Delta \sigma \approx t^{1/2}$ so $\Delta\sigma^{-2}$ versus $T$ should be a straight line approaching zero when $T \to T_{cmf}$. $T_{cmf}$ values for our samples are of about 0.13 ($x = 3$ wt.%) and 1.26 ($x = 1.0$ wt.%) higher than the values of $T_c$. 

![Graphs showing variation of $\Delta\sigma^{-2}$ versus $T$](https://digitalcommons.bau.edu.lb/stjournal/vol1/iss1/6)
The excess conductivities \( \Delta \sigma \) was calculated as function of \( t \) in the \( \ln - \ln \) plot for (nano-Ag)\(_{x}\)Cu\(_{0.5}\)Ti\(_{0.5}\)Ba\(_{2}\)Ca\(_{2}\)Cu\(_{3}\)O\(_{10+\delta}\), for \( x = 0.0 \) for two values \( T_c \) and \( T_c^{mf} \) as shown in Fig. 6. This figure shows that all regions affected by the difference of these values, while Esmaeili et al. [56] found that the regions did not affect by this difference. In the rest of this paper the \( \Delta \sigma \) is calculated as function of \( t \) for \( T_c^{mf} \) to avoid the arbitrary definitions of \( T_c \) such as midpoint of transition curve or the temperature of the maximum of \( \partial \rho (T) / \partial T \).

Figs. 6(a), (b) and (c) show \( \Delta \sigma \) as function of \( t \) in \( \ln - \ln \) plot for (nano-Ag)\(_{x}\)Cu\(_{0.5}\)Ti\(_{0.5}\)Ba\(_{2}\)Ca\(_{2}\)Cu\(_{3}\)O\(_{10+\delta}\), for \( x = 0.5, 1.5 \) and 3.0 wt. \% respectively. To compare the calculated results with the theoretical expectations, the values of \( \alpha \) are determined from the slopes of the linearly fitting and listed in Table 3. Evidently, each plot shows three distinct regions with various values of \( \alpha \). Above \( T_c \), the first region at greater temperature, the values of \( \alpha \) change from -1.11 to -1.31, indicating the existence of two-dimensional fluctuations. In this region the charge carriers move in \( \alpha \)-planes as a result of the HTSCs layered structure. As \( T \) decreased, a crossover to second region is observed, and the \( \alpha \) changes from -0.48 to -0.53, indicating the presence of three-dimensional fluctuations. In the 3D region the motion of the charge carriers is between the molecular planes and crossover from one plane to another. This means that the charge-carriers move with less resistivity in the whole sample before pairing (in a small range of temperature above \( T_c \)). The three to two dimensional crossover temperatures are computed from the intersection of the fitting lines and are recorded in Table 3. These data showed that the 3D regions shifted to higher temperatures as \( x \) increase up to 1.5 wt. \% then an opposite trend was observed for higher values of \( x \). The swing of 3D region to lower temperatures for \( x > 1.5 \) wt. \% provides an evidence of the increase of addition percentage leads to a decrease in phonon population which leads to a decrease in their basic density for the electron-phonon interactions resulting to a reduction of the critical region and hence the shift in the three-dimensional region to lower temperatures. Similar result was noticed for (Cu\(_{0.5}\)Ti\(_{0.5}\))-1234 substituted by Cd [16]. Finally, at Ginzburg temperature (\( T_G \)) a crossover between 3D fluctuations and the dynamic critical fluctuations occurred. Below \( T_G \), \( \alpha \) values change from -0.30 to -0.33, which are expected from the expectation of the 3D-xuniversality class, [57]. The E-model based on the coupling of a 2D superconducting order parameter with asymmetry-breaking field (SBF). We can see that the dimensional exponent shows a little deviation from the theoretical values given by the AL theory that could be due to the polycrystalline nature of the sample [33].

![Graph](image)

**Table 3:** The variation of \( \alpha(2D), \alpha(3D), \alpha(cr) \), \( T^{cr-3D}, T^{3D-2D} \) and \( T_c^{mf} \) for (nano-Ag)\(_{x}\)Cu\(_{0.5}\)Ti\(_{0.5}\)Ba\(_{2}\)Ca\(_{2}\)Cu\(_{3}\)O\(_{10+\delta}\), \( 0.0 \leq x \leq 3.0 \) wt. %

<table>
<thead>
<tr>
<th>( x ) (wt. %)</th>
<th>( \alpha(2D) )</th>
<th>( \alpha(3D) )</th>
<th>( \alpha(cr) )</th>
<th>( T_c^{cr-3D} ) (K)</th>
<th>( T^{3D-2D} ) (K)</th>
<th>( T_c^{mf} ) (K)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.0</td>
<td>-1.11</td>
<td>-0.48</td>
<td>-0.30</td>
<td>112.97</td>
<td>113.86</td>
<td>112</td>
</tr>
<tr>
<td>0.5</td>
<td>-1.17</td>
<td>-0.52</td>
<td>-0.32</td>
<td>116.35</td>
<td>117.51</td>
<td>115.40</td>
</tr>
<tr>
<td>1.0</td>
<td>-1.16</td>
<td>-0.53</td>
<td>-0.31</td>
<td>116.38</td>
<td>117.47</td>
<td>115.60</td>
</tr>
<tr>
<td>1.5</td>
<td>-1.31</td>
<td>-0.53</td>
<td>-0.30</td>
<td>122.06</td>
<td>122.89</td>
<td>121.20</td>
</tr>
<tr>
<td>2.0</td>
<td>-1.13</td>
<td>-0.52</td>
<td>-0.30</td>
<td>118.43</td>
<td>119.86</td>
<td>117.60</td>
</tr>
<tr>
<td>3.0</td>
<td>-1.14</td>
<td>-0.51</td>
<td>-0.33</td>
<td>109.20</td>
<td>111.79</td>
<td>108.00</td>
</tr>
</tbody>
</table>
Fig. 6: The variation of $\Delta \sigma$ with $t$ in ln-ln plot for (nano-Ag)$_x$(Cu$_{0.5}$Tl$_{0.5}$Ba$_2$Ca$_2$Cu$_3$O$_{10-\delta}$) for two values $T_c$ and $T_c^{mf}$: (a) 0.0 wt.%; (b) 1.0 wt.% (c) 3.0 wt.%.

$\xi_C(0)$ can be calculated from the values of $T^{3D-2D}$ for polycrystalline samples using equation (3) and their values are listed in table 4.

### Table 4: Values of $\xi_C(0)$, $d$, $v_F$, $E_F$ and $\nu$ for (nano-Ag)$_x$(Cu$_{0.5}$Tl$_{0.5}$Ba$_2$Ca$_2$Cu$_3$O$_{10-\delta}$) with $0.0 \leq x \leq 3.0$ wt.%

<table>
<thead>
<tr>
<th>$x$ (wt.%)</th>
<th>$\xi_C(0)$ (nm)</th>
<th>$d$ (nm)</th>
<th>$v_F \times 10^5$ (m/s)</th>
<th>$E_F \times 10^{-20}$ eV</th>
<th>$\nu \times 10^4$</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.0</td>
<td>2.30</td>
<td>2.64</td>
<td>1.85</td>
<td>0.10</td>
<td>303.60</td>
</tr>
<tr>
<td>0.5</td>
<td>1.41</td>
<td>87.83</td>
<td>1.16</td>
<td>0.04</td>
<td>0.10</td>
</tr>
<tr>
<td>1.0</td>
<td>1.25</td>
<td>16.89</td>
<td>1.04</td>
<td>0.03</td>
<td>2.19</td>
</tr>
<tr>
<td>1.5</td>
<td>1.05</td>
<td>44.51</td>
<td>9.16</td>
<td>0.02</td>
<td>0.22</td>
</tr>
<tr>
<td>2.0</td>
<td>3.82</td>
<td>60.37</td>
<td>3.25</td>
<td>0.30</td>
<td>1.60</td>
</tr>
<tr>
<td>3.0</td>
<td>9.71</td>
<td>98.67</td>
<td>7.59</td>
<td>1.64</td>
<td>3.87</td>
</tr>
</tbody>
</table>

$\xi_C(0)$ decreases as $x$ improves up to $x = 1.5$ wt.% and then reduces for further increase in $x$. Similar trend was noticed by Sato et al. [58] who found that the increase in Ag addition on Y-123 decreased $\xi_C(0)$. They attributed this behavior to suppression of density of the mobile carriers.
indicating that this addition changes the samples from over- to under-doped. The same behavior was observed by Mohammed [17] for \((\text{Cu}_{0.5}\text{Tl}_{0.5})-1223\) substituted by Ti and Khan et al. [15] for \((\text{Cu}_{0.5}\text{Tl}_{0.5})-1234\) substituted by Zn. The calculated values of Fermi velocity of the carriers using the equation: 

\[
v_F = \frac{5\text{k}_B\text{c}_e^2(0)}{2\text{K}}
\]

where \(\text{k}_B\) is the Boltzmann constant and \(\text{K} \approx 0.12\) is coefficient of proportionality [59], are listed in table 4. The values of \(v_F\) are found to be lower than that of the free electron \((v_F = 10^6 \text{ m.s}^{-1})\). Khan et al. [60] observed similar result. The Fermi energy is determined from the relation; 

\[
E_F = \frac{1}{2}m^*v_F^2,
\]

where \(m^* \approx 10m_0\) is the effective mass of the charge carrier, \(m_0\) is the carrier free mass [61] and are listed in table 4. The calculated Fermi energy are in the order of that achieved by Abou Aly et al. [62, 63] for \((\text{Cu}_{0.5}\text{Tl}_{0.5})-1223\) replaced by Presidium and Lanthanum and for \((\text{Tl,Hg})-1223\) substituted by Sm and Yb. It is obvious that the Fermi energy slightly decreases by increasing nano-Ag addition till \(x = 1.5\) wt.%. Then a reverse trend occur with \(x > 1.5\) wt.% which could be attributed to phase change. Finally, the values of the interlayer coupling \(v\), which is given by \(v = \left(\frac{2\pi}{d}\right)^2\) [9] are listed in table 4. They are lower than 1, verifying the weak coupling between the CuO2-planes and 3D-2D crossover regions [17].

4. CONCLUSIONS

A- In this work, the \((\text{nano-Ag})_x\text{Cu}_{0.5}\text{Tl}_{0.5}\text{Ba}_2\text{Ca}_2\text{Cu}_3\text{O}_{10-\delta}\) superconducting phase has been successfully synthesized via single step solid-state reaction technique.

B- The addition of nano-Ag to \(\text{Cu}_{0.5}\text{Tl}_{0.5}\text{Ba}_2\text{Ca}_2\text{Cu}_3\text{O}_{10-\delta}\) up to \(x = 1.5\) wt.% improved the volume fraction, grains connectivity and \(T_C\). A reverse trend was observed for \(x > 1.5\) wt.%. 

C- 2D, 3D and cr fluctuations regions were clearly observed. The sample with \(x = 0.15\) wt.% showed the lowest coherence length and Fermi velocity.

D- All the estimated values of \(\upsilon\) are less than one confirming the weak coupling between CuO2 planes and crossover between 3D and 2D regions.

ACKNOWLEDGEMENTS

The author of the present study wish to express their thanks to the superconductivity and metallic glass lab, Physics Department, Faculty of Science, Alexandria University, Alexandria, Egypt, for aiding with the experimental procedures.

REFERENCES


Bouchoucha, I., Azzouz, F. B., & Salem, M. B. (2011). Excess Conductivity Studies In Zn 0.95 Mn 0.05 O And Zno Added Yba 2 Cu 3 O Y Superconductors. *Journal of Superconductivity and Novel Magnetism*, 24(1-2), 345.


Ismail, S., Yahya, A. K., & Khan, N. A. (2013). Superconducting Fluctuation and Infrared Absorption of Cd-substituted Tl0. 9Bi0. 1Sr1. 8Yb0. 2Ca1− xCdxCu1. 99Fe0. 01O7− δ Ceramics. Ceramics International, 39, S257.


Khan, N. A., Rahim, M., & Mumtaz, M. (2012). Critical regime and suppression of the pseudo-gap in Cu0. 5Tl0. 5Ba2Ca2Cu3O10− δ superconductors via excess conductivity analyses. Physica C: Superconductivity, 478, 32.


Kong, W., & Abd-Shukor, R. (2010). Enhanced Electric Transport Properties of Nano Nife 2 O 4-Added (Bi 1.6 Pb 0.4) Sr 2 Ca 2 Cu 3 O 10 Superconductor. Journal of Superconductivity and Novel Magnetism, 23(2), 257.


Khan, N. A., Khurram, A. A., Firdous, U., Ullah, S., & Khan, S. (2012). Excess Conductivity of Pb-Doped (Cu0. 5− xPbxtl0. 5) Ba2Ca2Cu3O10− δ Superconductors. Physica C: Superconductivity, 474, 47.


Mohammed, N. H. (2013). The Excess Conductivity of (Cu0. 5Tl0. 5)-1223 Superconductor Substituted by Ti. Physica C: Superconductivity, 485, 95.

Mumtaz, M., Khan, N. A., Hasnain, S. M., & Ashraf, F. (2012). Superconductivity and Fluctuation-Induced Conductivity (FIC) Analysis of (Cu 0.5 Tl 0.5− x M x) Ba 2 Ca 2 Cu 3 O 10− δ. Journal of Superconductivity and Novel Magnetism, 25(7), 2291-2295.


- Rahim, M., & Khan, N. A. (2012). Suppressed Phonon Density and Para Conductivity of Cd Doped Cu0. 5Tl0. 5Ba2Ca3Cu4− yCdO12− δ (y= 0, 0.25, 0.5, 0.75) Superconductors. *Journal of alloys and compounds*, 513, 55.


- Şakiroğlu, S., & Kocaçak, K. (2011). The Effect Of Silver Substitution In Bi 1.7 Pb 0.3 Sr 2 Ca 2− X Ag X Cu 3 O Y. *Journal Of Superconductivity And Novel Magnetism*, 24(4), 1321-1325.


